

Product Specification

PE4272

SPDT Broadband UltraCMOS™ DC – 3 GHz RF Switch

Features

- High ESD tolerance of 1.5 kV
- Single-pin CMOS logic control
- Low insertion loss: 0.5 dB at 1000 MHz, 6 dP at 2000 MHz
- Isolation of 43 dB at 1000 MHz, 33.5 dB at 2000 MHz
- Typical input 1 dB compression point of +32 dBm
- Small 8-lead MSOP Jackage

Product Description

The PE4272 RF Switch is designed for the TV tuner, PCTV, set top box, DTV, DVR and general broadband applications. This device offers industry leading broadband linearity, 1.5 kV ESD tolerance and a simple CMOS interface. The device offers a simple alternative solution to pin diode and mechanical relay switches.

The PE4272 SPDT High Power RF Switch is manufactured on Peregrine's UltraCMOS™ process, a patented variation of silicon-on-insulator (SOI) technology on a sapphire substrate offering the performance of GaAs with the economy and integration of conventional CMOS.

Figure 1. Functional Diagram

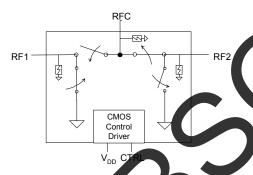


Figure 2. Rackage Type
8-lead MSO



Table 1. Electrical Specifications @ +25 °C, V_{DD} = 3 V ($Z_S = Z_L = 75 \Omega$)

Parameter	Conditions	Min	Тур	Max	Units
Operation Frequency ¹	DO-3000				MHz
Insertion Loss	1000 MHz 2000 MHz		0.5 0.6	0.6 0.7	dB
Isolation – RFC to RF1/RF2	1000 MHz 2000 MHz	41 31.5	43 33.5		dB
Isolation – RF1 to RF2	1000 MHz 2000 MHz	41 32	43 34		dB
Return Loss	1000 MHz 2000 MHz		19.5 16		dB
'ON' Switching Time ³	50% CTRL to 0.1 dB final value, 2 GHz		500	1000	ns
OFF' Switching Time3	50% CTRL to 25 dB isolation, 2 GHz		500	1000	ns
Video Feedthrough ^{2,3}			<3		mV_{pp}
Input 1 dB Compression ³	1000 MHz	30	32		dBm
Input IP3 ³	1000 MHz, 20 dBm input power		52		dBm

Notes:

- 1. Device linearity will begin to degrade below 5 MHz.
- 2. Measured with a 1 ns risetime, 0/3 V pulse and 500 MHz bandwidth.
- 3. Measured in a 50 Ω system.

Figure 3. Pin Configuration (Top View)

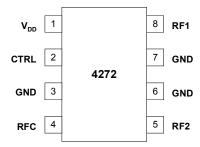


Table 2. Pin Descriptions

Pin No.	Pin Name	Description		
1	V_{DD}	Nominal +3 V supply connection.		
2	CTRL	CMOS logic level: High = RFC to RF1 signal path Low = RFC to RF2 signal path		
3	GND	Ground connection. Traces should be physically short and connected to ground plane for best performance.		
4	RFC	RF Common ports		
5	RF2	RF2 port. ⁴		
6	GND	Ground Connection. Traces should be physically short and connected to ground plane for best performance.		
7	GND	Ground Connection. Traces should be physically short and connected to ground plane for best performance.		
8	RF1	AF1 port4		

4. All R pins must be C blocked with an ext Note: series acitor or h at 0 VDC.

Table 3. Operating Ranges

Parameter	Min	Typ	Max	Units
V _{DD} Power Supply Voltage	2.7	3:0	3.3	V
I_{DD} Power Supply Current $(V_{DD} = 3 \text{ V}, \text{ CTRL} = 4 \text{ V})$		8	20	μΑ
Operating temperature range	-40		85	ů
Control Voltage High	0.7xV _{DD}			٧
Control Voltage Low			$0.3xV_{DD}$	V

Table 4. Absolute Maximum Ratings

Symbol	Parameter/Conditions	Min	Max	Units
V_{DD}	Power supply voltage	-0.3	4.0	V
Vı	Voltage on any input	-0.3	V _{DD} + 0.3	>
T _{ST}	Storage temperature range	-65	150	°C
$P_{\scriptscriptstyle IN}$	Input power (50·Ω)		34	dBm
V_{ESD}	ESD voltage (HBM, ML_STD 883 Method 3015.7)		1500	٧

ted in the above table. Exceeding may cause permanent device damag etional operation should be restricted to the mits in the Operating Flanges table. Exposure to bsolute maximum ratings for extended periods may affect device reliability.

Latch-Up Avoidand

Unlike conventional CMOS devices, UltraCMOS™ devices are immune to latch-up.

Electrostatic Discharge (ESD) Precautions

When handling this UltraCMOS™ device, observe the same precautions that you would use with ther ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the rating specified in Table 4.



Table 5. Single-pin Control Logic Truth Table

Control Voltages	Signal Path
Pin 1 $(V_{DD}) = V_{DD}$ Pin 2 $(CTRL) = High$	RFC to RF1
Pin 1 $(V_{DD}) = V_{DD}$ Pin 2 $(CTRL) = Low$	RFC to RF2

Table 6. Complementary-pin Control Logic Truth Table

Control Voltages	Signal Path
Pin 1 $(V_{DD}) = Low$ Pin 2 $(CTRL) = High$	RFC to RF1
Pin 1 (V _{DD}) = High Pin 2 (CTRL) = Low	RFC to RF2

Control Logic Input

The PE4272 is a versatile RF CMOS switch that supports two operating control modes; single-pin control mode and complementary-pin control mode.

Single-pin control mode enables the switch to operate with a single control pin (pin 2) supporting a +3-volt CNOS logic input, and requires a dedicated +3-volt power supply connection (pin 1). This mode of operation reduces the number of control lines required and simplifies the switch ontrol interface typically derived from a CMOS uProcessor No port.

omplementary-pin control mode allows the witch to operate using complementary control in CTRL and V_{CD} (pins 2 & 1), that can be directly driven by 3-volt CMOS logic or a suitable Processor 10 port. This enables the PE4272 to operate in positive control voltage mode within the PE4272 operating limits.



Evaluation Kit

The SPDT Switch Evaluation Kit board was designed to ease customer evaluation of the PE4272 SPDT switch. The RF common port is connected through a 75 Ω transmission line to the bottom F connector, J2. Port 1 and Port 2 are connected through 75 Ω transmission lines to two F connectors on either side of the board, J1 and J3. A through transmission line connects F connectors J4 and J5. This transmission line can be used to estimate the loss of the PCB over the environmental conditions being evaluated.

The board is constructed of a two metal layer FR4 material with a total thickness of 0.031". The bottom layer provides ground for the RF transmission lines. The transmission lines were designed using a coplanar waveguide with ground plane model using a trace width of 0.021", trace gaps of 0.030", dielectric thickness of 0.028", copper thickness of 0.0021" and ϵ_r of 4.3.

J6 provides a means for controlling the DC inputs to the device. The lower right pin (J6-2) is connected to the device CTRL input. The upper right pin is connected to the device V_{DD} input. Footprints for decoupling capacitors are provided on both and V_{DD} traces. It is the responsibility of t customer to determine proper supply decoupling for their design application. Removing components from the evaluation k ard has not shown to deal ade RF erfo

Figure 4. Evaluation Board Layouts

Peregrine specification 101/0243

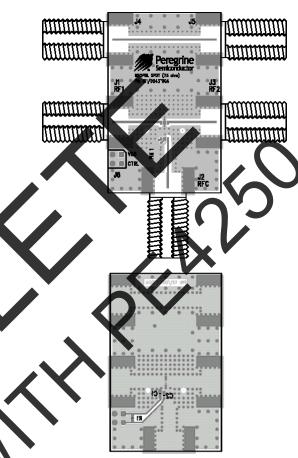


Figure 5. Evaluation Board Schematic Peregrine specification 102/0309

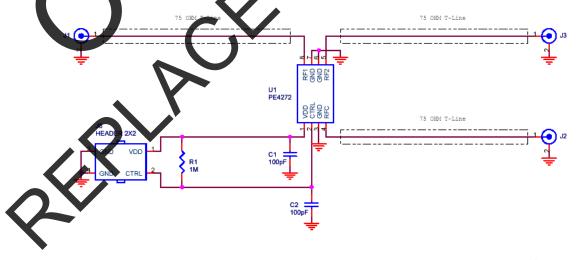




Figure 6. Insertion Loss: RFC-RF1 @ 25 °C

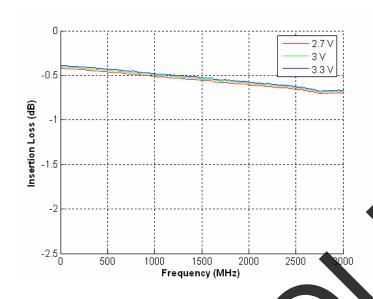


Figure 7. Insertion Loss: RFC-RF1 @ 3 V

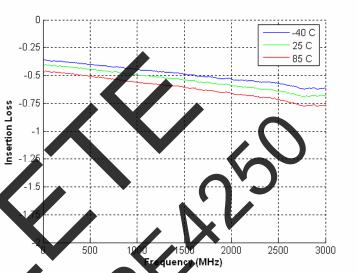


Figure 8. Insertion Loss: R C-RF2 @ 25 °C

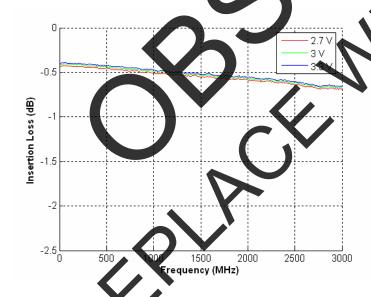


Figure 9. Insertion Loss: RFC-RF2 @ 3 V

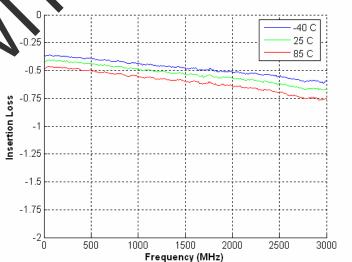




Figure 10. Isolation: RFC-RF1 @ 25 °C

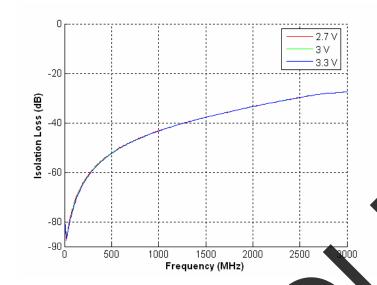


Figure 11. Isolation: RFC-RF1 @ 3 V

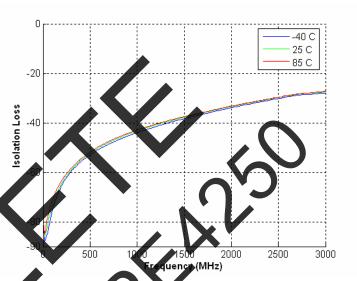


Figure 12. Isolation: RFC-R

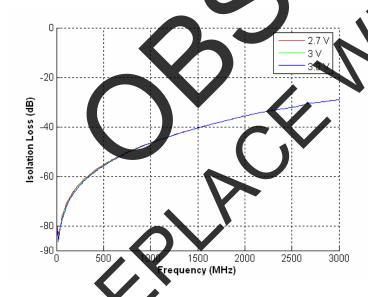


Figure 13. Isolation: RFC-RF2 @ 3 V

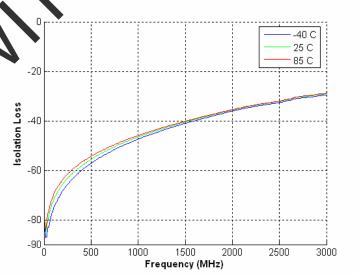




Figure 14. Isolation: RF1-RF2 @ 25 °C

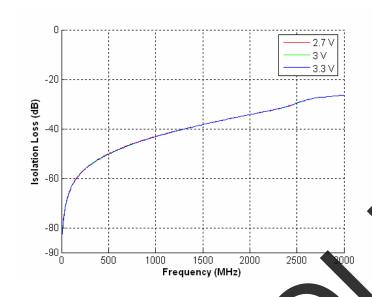


Figure 15. Isolation: RF1-RF2 @ 3 V

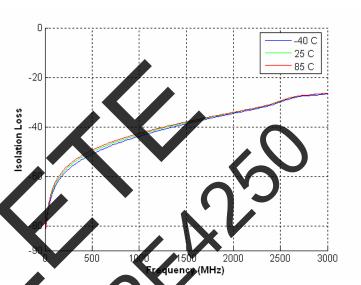


Figure 16. Return Loss: RFC-RF1

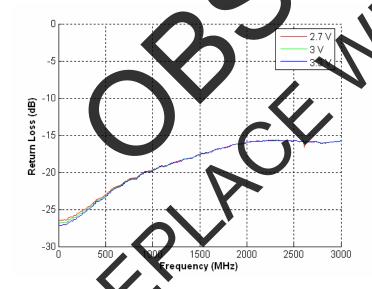


Figure 17. Return Loss: RFC-RF1 @ 3 V

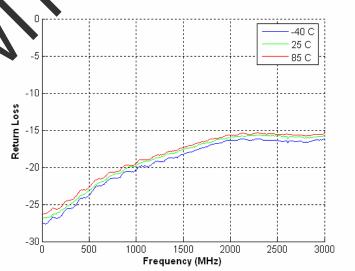




Figure 18. Return Loss: RFC-RF2 @ 25 °C

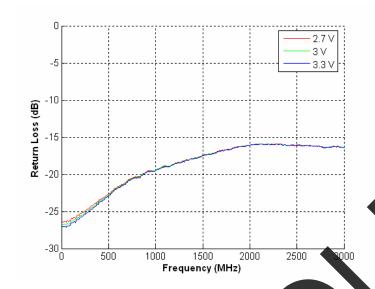


Figure 19. Return Loss RFC-RF2 @ 3 V

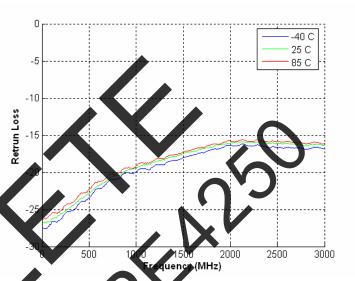
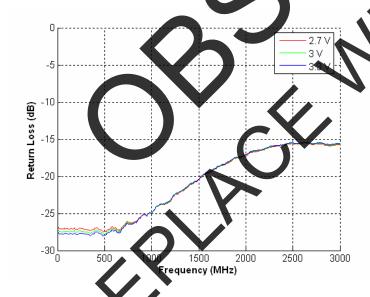


Figure 20. Return Loss: RFC-RF1/RF2 @ 25 °C



21. Return Loss: RFC-RF1/RF2 @ 3 V

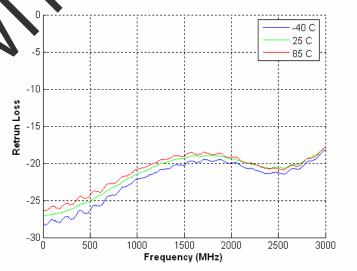




Figure 22. Package Drawing

8-lead MSOP

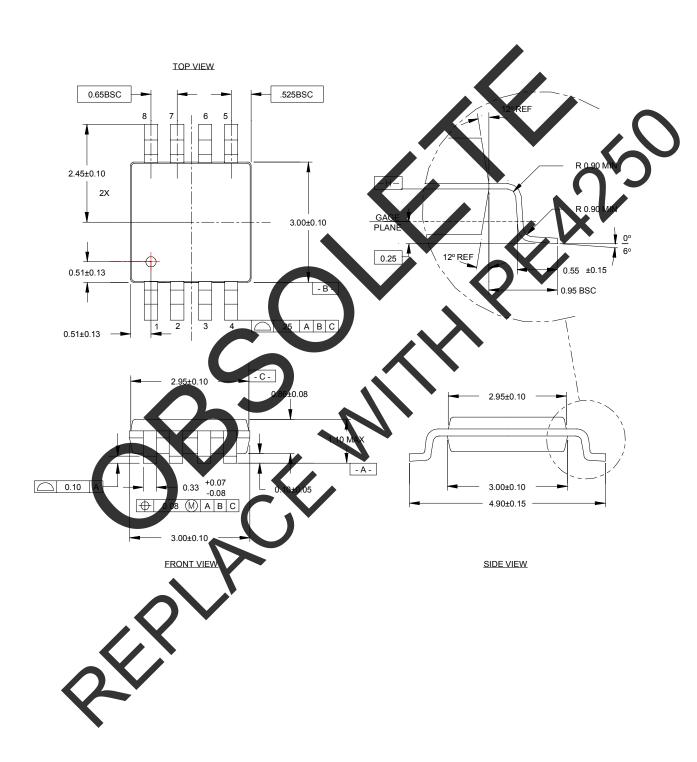




Figure 23. Tape and Reel Specifications

8-lead MSOP

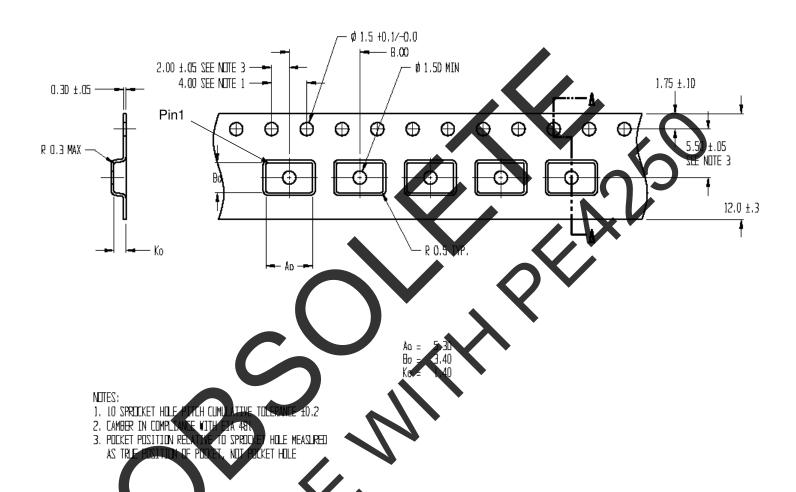


Table 7. Ordering Information

Order Code	Part Marking	Description	Package	Shipping Method
4272-01	4272	PE4272-08MSOP-50A	8-lead MSOP	50 units / Tube
4272-02	4272	PE4272-08MSOP-2000C	8-lead MSOP	2000 units / T&R
4272-00	PE4272-EK	PE4272-08MSOP-EK	Evaluation Kit	1 / Box
4272-51	4272	PE4272G-08MSOP-50A	Green 8-lead MSOP	50 units / Tube
4272-52	4272	PE4272G-08MSOP-2000C	Green 8-lead MSOP	2000 units / T&R



Sales Offices

The Americas

Peregrine Semiconductor Corporation

9450 Carroll Park Drive San Diego, CA 92121 Tel 858-731-9400 Fax 858-731-9499

Europe

Peregrine Semiconductor Europe

Bâtiment Maine 13-15 rue des Quatre Vents F- 92380 Garches, France Tel: +33-1-47-41-91-73 Fax: +33-1-47-41-91-73

Space and Defense Products

Americas:

Tel: 505-881-0438 Fax: 505-881-0443 Europe, Asia Pacific:

180 Rue Jean de Guiramand

13852 Aix-En-Provence cedex 3, Fra

Tel: +33(0) 4 4239 3361 Fax: +33(0) 4 4239 7227

North Asia Pacific

Peregrine Semiconductor K.K.

5A-5, 5F Imperial Tower 1-1-1 Uchisaiwaicho Chiyoda-ku Tokyo 100-0011

Tel: +81-3-3502-5211 Fax: +81-3-3502-521

Peregrine Semiconductor, Korea

Kolon Tripo

ong, Bundang-gu, Seongr yeonggi-do, 463-480 S. Korea

Tel: ±82-31-728-4300 +82-31-728-4305

Asia Pacif

Peregrine Semiconductor, China

hanghai, 2004 Γel: +86-21**₄**

in your area, ple For a list of representative efer to our Web site a www.psemi.com

Data Sheet Identification

Advance Information

The product is in a formative or design stag sheet contains design target specifications for product development. Specifications and features in any manner without notice.

Preliminary Specification

The data sheet contains preliminary data. Additional data may be added at a later date. Peregrine reserves the right to change specifications at any time without notice in order to supply the best possible product.

ecification

The data sheet contains final data. In the event Peregrine decides to change the specifications, Peregrine will notify customers of the intended changes by issuing a DCN (Document Change Notice).

The information in this data sheet is believed to be reliable. However, Peregrine assumes no liability for the use of this information. Use shall be entirely at the user's own risk.

No patent rights or licenses to any circuits described in this data sheet are implied or granted to any third party.

Peregrine's products are not designed or intended for use in devices or systems intended for surgical implant, or in other applications intended to support or sustain life, or in any application in which the failure of the Peregrine product could create a situation in which personal injury or death might occur. Peregrine assumes no liability for damages, including consequential or incidental damages, arising out of the use of its products in such applications.

The Peregrine name, logo, and UTSi are registered trademarks and UltraCMOS and HaRP are trademarks of Peregrine Semiconductor Corp.